

HD1760JL

Very high voltage NPN power transistor for high definition and slim CRT display

Features

- State-of-the-art technology: diffused collector "enhanced generation" EHVS1
- Wide range of optimum drive conditions
- Stable performance versus operating temperature variation

Applications

■ High-definition and slim CRT TV and monitors

Description

The HD1760JL is manufactured using Diffused Collector in Planar technology adopting new and Enhanced High Voltage Structure 1 (E.H.V.S.1) developed to fit High-Definition CRT display. The new HD product series show improved silicon efficiency bringing updated performance to the Horizontal Deflection stage.



Internal schematic diagram



| | whe 1. Device summ | oducits | (1) B O SC06960 | $E \circ (3)$ |
|---|--------------------|----------|-----------------------|---------------|
| Ч | Part number | Marking | Package | Packaging |
| _ | HD1760JL | HD1760JL | TO-264 | Tube |

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Electrical ratings

| Table 2. | Absolute | maximum | rating |
|----------|----------|---------|--------|
|----------|----------|---------|--------|

| Symbol | Parameter | Value | Unit |
|------------------|---|------------|------|
| V_{CES} | Collector-emitter voltage (V _{BE} = 0) | 1700 | V |
| V _{CEO} | Collector-emitter voltage (I _B = 0) | 800 | V |
| V_{EBO} | Emitte-base voltage ($I_{\rm C} = 0$) | 10 | V |
| Ι _C | Collector current | 36 | А |
| I _{CM} | Collector peak current (t _P < 5ms) | 54 | А |
| Ι _Β | Base current | 18 | А |
| I _{BM} | Base peak current (t _P < 5ms) | 27 | А |
| P _{TOT} | Total dissipation at $T_c = 25^{\circ}C$ | 200 | W |
| T _{STG} | Storage temperature | -55 to 150 | °C |
| Τ _J | Max. operating junction temperature | 150 | °C |
| Table 3. | Thermal data | dulu | |
| Symbol | Baramatar | Value | Unit |

Thermal data Table 3.

| | Symbol | Parameter | 8 | Value | Unit |
|--------|-------------------|----------------------------------|------|-------|------|
| | R _{thJC} | Thermal resistance junction case | Max | 0.625 | °C/W |
| opsole | ste P | roducils) obs | 2161 | | |

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Electrical characteristics

 $(T_{CASE} = 25^{\circ}C; unless otherwise specified)$

| Table 4. | Electrical characteristics | 5 | | | | |
|--------------------------------------|--|---|------|------------|----------|----------|
| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
| I _{CES} | Collector cut-off current (V _{BE} = 0) | $V_{CE} = 1700V$ $V_{CE} = 1700V$ $T_{C} = 125^{\circ}C$ | | | 0.2 2 | mA mA |
| I _{EBO} | Emitter cut-off current $(I_{\rm C} = 0)$ | V _{EB} = 5V | | | 10 | μA |
| V _{CEO(sus)} ⁽¹⁾ | Collector-emitter sustaining voltage (I _B = 0) | I _C = 10mA | 800 | | | ۷ |
| V_{EBO} | Emitter-base voltage (I _C = 0) | I _E = 10mA | 10 | | | V |
| V _{CE(sat)} (1) | Collector-emitter saturation voltage | I _C = 18A I _B = 4.5A | | | 20 | v |
| V _{BE(sat)} (1) | Base-emitter saturation voltage | I _C = 18A I _B = 4.5A | 2 | J.C | 1.5 | V |
| h _{FE} | DC current gain | $I_{C} = 2A$ $V_{CE} = 5V$ $I_{C} = 18A$ $V_{CE} = 5V$ | 5 | 30 | 8.5 | |
| t _s t _f | Inductive load Storage time Fall time | $\begin{array}{ll} I_{C} = 12A & f_{h} = 32 \; \text{KHz} \\ I_{B(on)} = 1A & I_{B(off)} = -6.9A \\ V_{CE(fly)} = 1340V \\ V_{BE(off)} = -2.7V \\ I_{BB(on)} = 0.8 \mu \text{H} \end{array}$ | | 2.6 300 | | μs ns |
| t _s t _f | Inductive load Storage time Fall time | $\label{eq:loss} \begin{array}{ll} I_{C} = 8A & f_{h} = 100 \text{kHz} \\ I_{B(on)} = 1.3A & I_{B(off)} = -5.8A \\ V_{CE(fly)} = 1300V \\ V_{BE(off)} = -2.7V \\ L_{BB(on)} = 0.25 \mu\text{H} \end{array}$ | | 2 110 | | μs ns |

 Table 4.
 Electrical characteristics

1. Pulsed duration = 300 ms, duty cycle £1.5%.



2.1 **Electrical characteristics (curve)**

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V_{CE}=1.5V

^{3 4 6 8}10^{0 2}

10⁰ 10^{-1 2}



6A 5A 25 4A 30 3A 20 2A 20 15 1 A



 $T_c = 100 °C$

 $10^{12} 10^{12} 10^{12}$

V_{BE(off)}=-5V,L_{BB(off)}=0

T_c = 100 °C

 $\frac{3468}{10^{12}34}$

 $V_{CE}(V)$ HV38270

 $V_{CE} = 5V$

3

2



Figure 8. Base-emitter saturation voltage



Figure 9. Power losses

Figure 10. Power losses



Figure 11. Inductive load switching time Figure 12. Inductive load switching time



3 Test circuit





Figure 14. Reverse biased safe operating area test circuit



4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

obsolete Product(s). Obsolete Product(s)



| DIM. | mm. | | | inch | | |
|------|-------|------|-------|-------|-------|-------|
| DIM. | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.80 | | 5.20 | 0.189 | | 0.205 |
| D | 2.50 | | 3.10 | 0.098 | | 0.122 |
| E | 0.50 | 0.60 | 0.85 | 0.020 | 0.24 | 0.033 |
| F | 0.90 | 1.00 | 1.25 | 0.036 | 0.039 | 0.049 |
| G | 10.30 | | 11.50 | 0.406 | | 0.453 |
| G1 | | 5.45 | | | 0.215 | |
| н | 19.80 | | 20.20 | 0.780 | | 0.795 |
| L3 | 25.80 | | 26.20 | 1.016 | | 1.031 |
| L5 | 5.80 | | 6.20 | 0.228 | | 0.244 |
| L7 | 19.50 | | 20.50 | 0.768 | | 0.807 |
| Ν | 2.30 | | 2.70 | 0.091 | | 0.106 |
| R | 4.7 | | 5.10 | 0.185 | | 0.201 |
| DIA | 3.10 | | 3.50 | 0.122 | | 0.138 |

Table 5. TO-264 mechanical data







5 Revision history

| Date | Revision | Changes | |
|-------------|----------|--|--|
| 17-Oct-2005 | 1 | Initial release. | |
| 03-Nov-2005 | 2 | h _{FE} value has been changed on <i>Table 4</i> | |
| 14-Jun-2007 | 3 | Complete version: new Section 2.1 inserted | |

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